

2 N 3313	USA,Mot	Ge-P	=2N3311: 60V	38a	TO-36				2N1981...82, 2N2079...80, 2N2491...93
2 N 3314	USA,Mot	Ge-P	=2N3311: hFE=100...200	38a	TO-36				2N1980...82, 2N2075...82, 2N2491...93
2 N 3315	USA,Mot	Ge-P	=2N3311: 45V, hFE=100...200	38a	TO-36				2N1980...82, 2N2075...82, 2N2491...93
2 N 3316	USA,Mot	Ge-P	=2N3311: 60V, hFE=100...200	38a	TO-36				2N1981...82, 2N2079...80, 2N2491...93
2 N 3317	Sem,Tdy,Upi	Si-P	Chopper, 30/30/30V, 0,05A, 0,15W	2a	TO-18				2N2946
2 N 3318	Sem,Tdy,Upi	Si-P	Chopper, 15/15/15V, 0,05A, 0,15W	2a	TO-18				2N2945
2 N 3319	Sem,Tdy,Upi	Si-P	Chopper, 10/6/10V, 0,05A, 0,15W	2a	TO-18				2N2944
2 N 3320	Idi,Ssi,Upi	Ge-P	S, 15V, 0,1A, 0,06W, <20/35ns	2a	TO-18				2N705, 2N960...67, 2N2955...57
2 N 3321	Idi,Ssi,Upi	Ge-P	S, 12V, 0,1A, 0,06W, <20/40ns	2a	TO-18				2N705, 2N960...67, 2N2955...57
2 N 3322	Idi,Ssi,Upi	Ge-P	S, 12V, 0,1A, 0,06W, <20/45ns	2a	TO-18				2N705, 2N960...67, 2N2955...57
2 N 3323	USA,Mot	Ge-P	AM/FM, 35V, 0,1A, 0,15W, >200MHz	2a	TO-18				AF 109R, AF 139, AF 239(S), 2N3283...86
2 N 3324	USA,Mot	Ge-P	AM/FM, 35V, 0,1A, 0,15W, >200MHz	2a	TO-18				AF 109R, AF 139, AF 239(S), 2N3283...86
2 N 3325	USA,Mot	Ge-P	AM/FM, 35V, 0,1A, 0,15W, >200MHz	2a	TO-18				AF 109R, AF 139, AF 239(S), 2N3283...86
2 N 3326	USA,Fch,Itt	Si-N	S, 60V, 0,8A, 0,8W, >250MHz	2a	TO-5				BSW 51...54, BSX 32, 2N2218...19(A), ++
2 N 3327	Sca,Ssi	Si-N	HF P, 65V, 2A, 20W, >100MHz	49a	TO-60				BLY 59, 2N3375
2 N 3328	Isi,Six,Tix	P-FET	Uni, 20V, Idss<1mA, Up<6V	5n	TO-72				
2 N 3329	USA,Mot,Tix	P-FET	=2N2497:	5n	TO-72				*2N2497
2 N 3330	USA,Mot,Tix	P-FET	=2N2498:	5n	TO-72				*2N2498
2 N 3331	USA,Mot,Tix	P-FET	=2N2499:	5n	TO-72				*2N2499
2 N 3332	USA,Mot,Tix	P-FET	=2N2500:	5n	TO-72				*2N2500
2 N 3333	Tix	P-FET	Dual, 20V, Idss<1mA, Up<1,6V, ΔUgs<15mV	10-FLP	TO-89				-
2 N 3334	Tix	P-FET	=2N3333: ΔUgs<20mV	10-FLP	TO-89				-
2 N 3335	Tix	P-FET	=2N3333: ΔUgs<40mV	10-FLP	TO-89				-
2 N 3336	Tix	P-FET	=2N3333: ΔUgs<50mV	10-FLP	TO-89				-
2 N 3337	Fch,Sgs,++	Si-N	HF,IF, 40V, 0,05A, 0,3W, >400MHz	5g	TO-72				BF 198...199, BF 224...225, BF 596...597,++
2 N 3338	Fch,Sgs,++	Si-N	HF,IF, 40V, 0,05A, 0,3W, >400MHz	5g	TO-72				BF 198...199, BF 224...225, BF 596...597,++
2 N 3339	Fch,Sgs,++	Si-N	HF,IF, 40V, 0,05A, 0,3W, >400MHz	5g	TO-72				BF 198...199, BF 224...225, BF 596...597,++
2 N 3340	USA	Si-N	Uni, 30V, 0,03A, 0,4W, >70MHz	2a	TO-46				BC 168, BC 183, BC 238, BC 548, ++
2 N 3341	USA	Si-P	Uni, 30V, 0,03A, 0,4W, >50MHz	2a	TO-46				BC 213, BC 258, BC 308, BC 558, ++
2 N 3342	USA	Si-P	Chopper, 20/8/20V, 0,05A, 0,25W, <150/280ns	2a	TO-5				2N2944
2 N 3343	USA	Si-P	Chopper, 25/8/25V, 0,05A, 0,25W	2a	TO-5				2N2944
2 N 3344	USA	Si-P	Chopper, 30/30/30, 0,05A, 0,25W	2a	TO-5				2N2946
2 N 3345	USA	Si-P	Chopper, 50/50/50, 0,05A, 0,25W	2a	TO-5				2N2946
2 N 3346	USA	Si-P	Chopper, 50/50/50, 0,05A, 0,25W	2a	TO-5				2N2946
2 N 3347	Mic,Nsc,Ray	Si-P	Dual, In, 60/45V, 0,03A, 0,6W, >60MHz, hFE=40...300	TO-77	(CBE-EBC-)				BFX 36, 2N3806...11, 2N4015...16
	Sca,Sgs,Tix		F<4dB(1K), ΔhFE=0,9...1, ΔUbe<-5mV						
2 N 3348		Si-P	=2N3347: ΔhFE=0,8...1, ΔUbe<10mV	TO-77	(CBE-EBC-)				BFX 36, 2N3806...11, 2N4015...16
2 N 3349		Si-P	=2N3347: ΔhFE=0,6...1, ΔUbe<20mV	TO-77	(CBE-EBC-)				BFX 36, 2N3806...11, 2N4015...16
2 N 3350		Si-P	=2N3347: hFE=100...300	TO-77	(CBE-EBC-)				BFX 36, 2N3806...11, 2N4015...16
2 N 3351		Si-P	=2N3347: hFE=100...300, ΔhFE=0,8...1, ΔUbe<10mV	TO-99	(CBE-EBC-)				BFX 36, 2N3806...11, 2N4015...16
2 N 3352		Si-P	=2N3347: hFE=100...300, ΔhFE=0,6...1, ΔUbe<20mV	TO-77	(CBE-EBC-)				BFX 36, 2N3806...11, 2N4015...16
2 N 3365	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>0,8mA, Up<12V	2b	TO-18				-
2 N 3366	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>0,2mA, Up<7V	2b	TO-18				2N4119
2 N 3367	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>0,05mA, Up<2,5V	2b	TO-18				2N4118
2 N 3368	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>2mA, Up<12V	2b	TO-18				2SK113
2 N 3369	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>0,5mA, Up<12V	2b	TO-18				-
2 N 3370	USA,Mot,Tix	N-FET	Uni, In, 40V, Idss>0,1mA, Up<3,2V	2b	TO-18				2N4118
2 N 3371	Idi,Spe,Tix	Ge-P	VHF, In, 25V, 0,1A, 0,15W, >400MHz	2a	TO-18				AF 139, AF 239(S), 2N3283...86
2 N 3374	Sty	Si-N	HF/S, 80V, 0,5A, PQ=2,8W(130MHz)	2a	TO-5				BFS 23, BLY 34, 2SC2419
2 N 3375	USA,EUR	Si-N	VHF/UHF P, 65V, 1,5A, PQ=3W(400MHz)	49a	TO-60				-
2 N 3376	Nsc,Six,++	P-FET	Uni, 30V, Idss>0,6mA, Up<5V	5n	TO-72				-
2 N 3377	Nsc,Six,++	P-FET	=2N3376:	=24					-
2 N 3378	Nsc,Six,++	P-FET	Uni, 30V, Idss>3mA, Up<5V	5n	TO-72				-
2 N 3379	Nsc,Six,++	P-FET	=2N3378:	=24					-
2 N 3380	Nsc,Six,++	P-FET	Uni, 30V, Idss>3mA, Up<9,5V	5n	TO-72				-
2 N 3381	Nsc,Six,++	P-FET	=2N3380:	=24					-
2 N 3382	Nsc,Six,++	P-FET	Uni, 30V, Idss>3mA, Up<5V	5n	TO-72				-
2 N 3383	Nsc,Six,++	P-FET	=2N3382:	=24					-
2 N 3384	Nsc,Six,++	P-FET	Uni, 30V, Idss>15mA, Up<5V	5n	TO-72				-
2 N 3385	Nsc,Six,++	P-FET	=2N3384:	=24					-
2 N 3386	Nsc,Six,++	P-FET	Uni, 30V, Idss>15mA, Up<9,5V	5n	TO-72				-
2 N 3387	Nsc,Six,++	P-FET	=2N3386:	=24					-
2 N 3388	Ssi,Stc,Tra	Si-N	Nixie, S, 125V, 2,5mA, 0,6W, >36MHz	2a	TO-5				BF 257...259, BF 657...659, 2N5058...59, ++
2 N 3389	Ssi,Stc,Tra	Si-N	Nixie, S, 195V, 7mA, 0,6W, >36MHz	2a	TO-5				BF 258...259, BF 658...659, 2N5058...59, ++
2 N 3390	USA,Mic,Tho	Si-N	Uni, 25V, 0,1A, 0,36W, 140MHz, hFE=400...800	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3391(A)	USA,Mic,Tho	Si-N	=2N3390: 160MHz, hFE=250...500	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3392	USA,Mic,Tho	Si-N	=2N3390: >120MHz, hFE=150...300	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3393	USA,Mic,Tho	Si-N	=2N3390: >120MHz, hFE=90...180	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3394	USA,Mic,Tho	Si-N	=2N3390: >120MHz, hFE=55...110	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3395	USA,Mic,Tho	Si-N	=2N3390: hFE=150...500	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3396	USA,Mic,Tho	Si-N	=2N3390: hFE=90...500	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3397	USA,Mic,Tho	Si-N	=2N3390: hFE=55...500	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3398	USA,Mic,Tho	Si-N	=2N3390: hFE=55...800	7c	TO-98	BC 546	7a		BC 168, BC 183, BC 238, BC 548, ++
2 N 3399	Amp,Ssi,Sty	Ge-P	UHF, 20V, 7mA, 0,08W, >400MHz	5g	TO-72				AF 139, AF 239(S), 2N3283...86
2 N 3400	Cen,Sty	Ge-P	S, 20V, 0,1A, 0,15W, <90/260ns	2a	TO-9				2N2635, 2N2955...57
2 N 3401	Tdy	Si-P	Chopper, 25/25/25V, 0,1A, 0,25W	2a	TO-5				2N2945
2 N 3402	USA,Mic,Tho	Si-N	Uni, 25V, 0,5A, 0,56W, hFE=75...225	7c°	TO-92°	BC 639	7c		BC 337...338, BC 635, BC 637, BC 639, ++
2 N 3403	USA,Mic,Tho	Si-N	=2N3402: hFE=180...540	7c°	TO-92°	BC 639	7c		BC 337...338, BC 635, BC 637, BC 639, ++
2 N 3404	USA,Mic,Tho	Si-N	=2N3402: 50V	7c°	TO-92°	BC 639	7c		BC 337, BC 637, BC 639, 2SD667, ++
2 N 3405	USA,Mic,Tho	Si-N	=2N3402: 50V, hFE=180...540	7c°	TO-92°	BC 639	7c		BC 337, BC 637, BC 639, 2SD667, ++
2 N 3406	Gen	UJT-P	70/60V, 0,45W, I _v >8mA	5	TO-33				-
2 N 3407	Mot,Sty	Si-N	HF, 35V, 0,1A, 0,2W, >300MHz	5g	TO-72				BF 198...199, BF 224...225, BF 596...597,++
2 N 3408	Mot,Sty	Si-P	HF Dry,Out, 40V, 0,5A, 4W, >200MHz	49a					-
2 N 3409	Mot,Sgs,++	Si-N	Dual, In, 60/30V, 0,5A, 0,6W, >250MHz, hFE=50...200	TO-77	(CBE-EBC-)				-
			F<4dB(1KHz), ΔhFE=0,8...1, ΔUbe<10mV						-
2 N 3410	Mot,Sgs,++	Si-N	=2N3409: ΔhFE=0,9...1, ΔUbe<10mV	TO-77	(CBE-EBC-)				-
2 N 3411	Mot,Sgs,++	Si-N	=2N3409: ΔhFE=0,9...1, ΔUbe<5mV	TO-77	(CBE-EBC-)				-
2 N 3412	Csr,Etc,Idi	Ge-P	HF, 20V, 0,1A, 0,06W, >100MHz	2a	TO-5				2N3283...86, (AF 106, AF 109R, AF 306)?
2 N 3413	Sca,Sty	Ge-P	S, Chopper, 150/150/150V, -0,2A, 0,4W	2a	TO-5				-
2 N 3414	USA,Mic,Tho	Si-N	=2N3402: 0,36W	7c	TO-98	BC 639	7c		*2N3402
2 N 3415	USA,Mic,Tho	Si-N	=2N3403: 0,36W	7c	TO-98	BC 639	7c		*2N3403
2 N 3416	USA,Mic,Tho	Si-N	=2N3404: 0,36W	7c	TO-98	BC 639	7c		*2N3404
2 N 3417	USA,Mic,Tho	Si-N	=2N3405: 0,36W	7c	TO-98	BC 639	7c		*2N3405